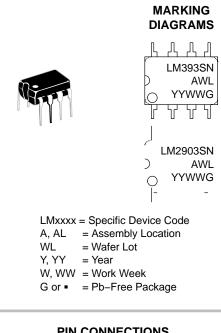
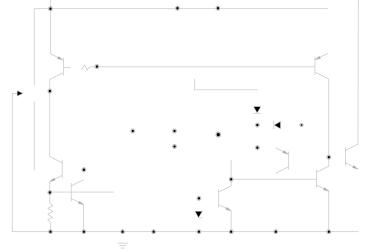
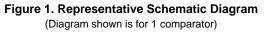


### Wh Semiconductor

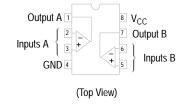
http://onsemi.com











#### **ORDERING INFORMATION**

See detailed marking information and ordering and shipping information on page 7 of this data sheet.

## LM393S, LM2903S

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V <sub>CC</sub>	+36 or ±18	V
Input Differential Voltage	V <sub>IDR</sub>		

## LM393S, LM2903S

			LM393	3S		LM290	35	
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage (Note 3)	V <sub>IO</sub>							mV
$T_A = 25^{\circ}C$		-	±1.0	±5.0	-	±2.0	±7.0	
$T_{low} \le T_A \le T_{high}$		-	-	±9.0	-	±9.0	±15	
Input Offset Current	I <sub>IO</sub>							nA
$T_A = 25^{\circ}C$		-	±5.0	±50	-	±5.0	±50	
$T_{low} \le T_A \le T_{high}$		-	-	±150	-	±50	±200	
Input Bias Current (Note 4)	I <sub>IB</sub>							nA

# **ELECTRICAL CHARACTERISTICS** (V<sub>CC</sub> = 5.0 Vdc, $T_{low} \le T_A \le T_{high}$ , unless otherwise noted.)

### LM393S, LM2903S

#### **APPLICATIONS INFORMATION**

These dual comparators feature high gain, wide bandwidth characteristics. This gives the device oscillation tendencies if the outputs are capacitively coupled to the inputs via stray capacitance. This oscillation manifests itself during output transitions (V<sub>OL</sub> to V<sub>OH</sub>). To alleviate this situation, input resistors <10 k $\Omega$  should be used. The addition of positive feedback (<10 mV) is also recommended. It is good design practice to ground all unused pins.

Differential input voltages may be larger than supply voltage without damaging the comparator's inputs. Voltages more negative than -0.3 V should not be used.

D1 prevents input from going negative by more than 0.6 V.

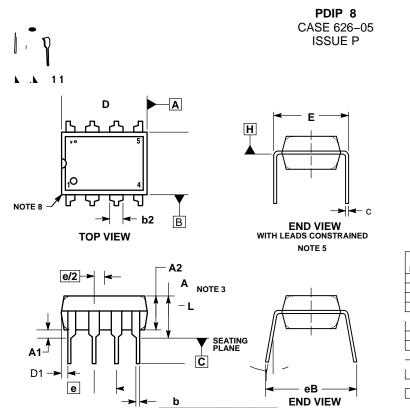
10

Figure 2. Zero Crossing Detector (Single Supply) Figure 3. Zero Crossing Detector (Split Supply)

Figure 4. Free–Running Square–Wave Oscillator

Figure 5. Time Delay Generator

Figure 6. Comparator with Hysteresis



**0.010** 

SIDE VIEW

CAMBM

NOTE 6

	INC	HES		
DIM	MIN	MAX		
Α		0.210		
A1	0.015			
A2	0.115	0.195	2.92	4.95
b	0.014	0.022		
С	0.008	0.014		
D	0.355	0.400		
D1	0.005			
Е	0.300	0.325		
е	0.100 BSC			
L	0.115	0.150	2.92	3.81
		0		0

DATE 22 APR 2015

#### GENERIC **MARKING DIAGRAM\*** . . . .

Ь	Д	Д	1
XX	XXX	XX	XX
Þ		A١	NL
0	ΥY	WV	VG
Ţ	Ъ		Г

- XXXX = Specific Device Code
- = Assembly Location А
- WL = Wafer Lot
- = Year YΥ
- WW = Work Week G
  - = Pb-Free Package

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